

# MA5J002D

## Silicon epitaxial planar type

For high speed switching circuits

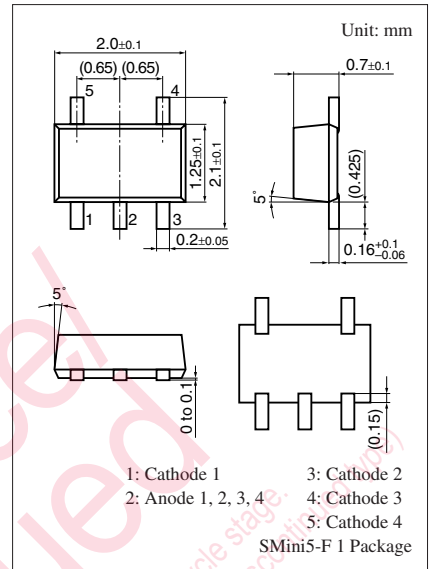
### ■ Features

- Includes 4 elements of anode common connection
- Parts reduction is possible
- Ideal for surge voltage absorption

### ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

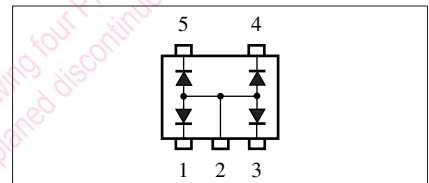
| Parameter                                      | Symbol    | Rating      | Unit             |
|--|-----------|-------------|------------------|
| Reverse voltage                                | $V_R$     | 80          | V                |
| Maximum peak reverse voltage                   | $V_{RM}$  | 80          | V                |
| Forward current *1                             | $I_F$     | 100         | mA               |
| Peak forward current *1                        | $I_{FM}$  | 225         | mA               |
| Non-repetitive peak forward surge current *1,2 | $I_{FSM}$ | 500         | mA               |
| Junction temperature                           | $T_j$     | 150         | $^\circ\text{C}$ |
| Storage temperature                            | $T_{stg}$ | -55 to +150 | $^\circ\text{C}$ |

Note) \*1: Value in single diode used.  
\*2:  $t = 1\text{ s}$



Marking Symbol: M5C

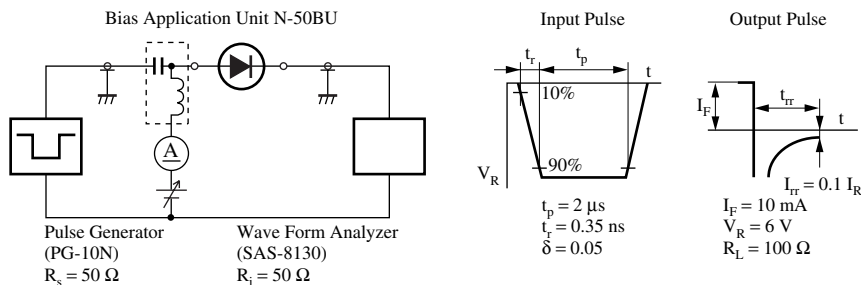
Internal Connection

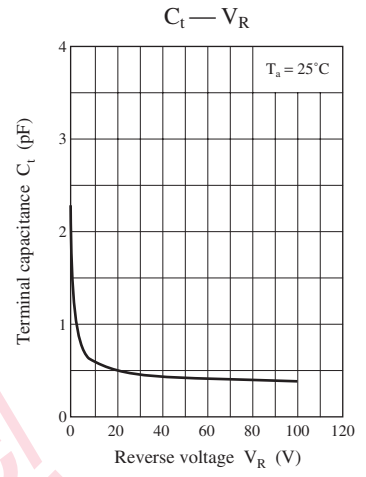
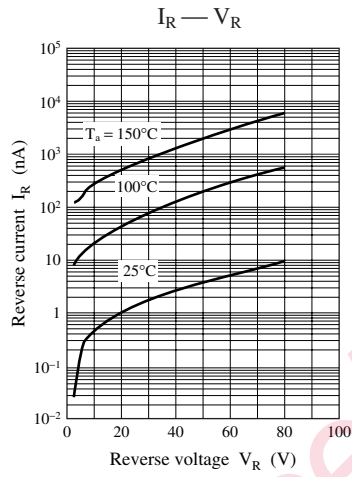
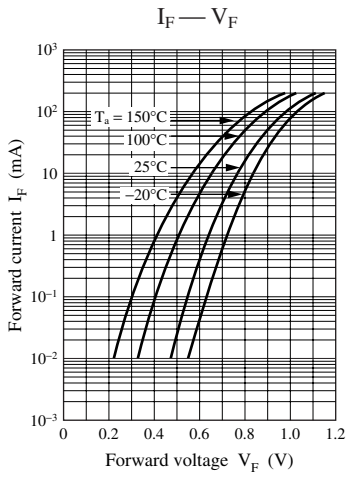


### ■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

| Parameter               | Symbol   | Conditions  | Min | Typ | Max | Unit |
|-------------------------|----------|---|-----|-----|-----|------|
| Forward voltage         | $V_F$    | $I_F = 100\text{ mA}$   |     |     | 1.3 | V    |
| Reverse voltage         | $V_R$    | $I_R = 100\ \mu\text{A}$  | 80  |     |     | V    |
| Reverse current         | $I_R$    | $V_R = 70\text{ V}$   |     |     | 100 | nA   |
| Terminal capacitance    | $C_t$    | $V_R = 0\text{ V}, f = 1\text{ MHz}$  |     |     | 3.5 | pF   |
| Reverse recovery time * | $t_{rr}$ | $I_F = 10\text{ mA}, V_R = 6\text{ V}$<br>$I_{rr} = 0.1 I_R, R_L = 100\ \Omega$ |     |     | 5.0 | ns   |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring method for diodes.  
2. Absolute frequency of input and output is 100 MHz.  
3. \*:  $t_{rr}$  measurement circuit





Maintenance/Discontinued

Maintenance/Discontinued includes following four Product lifecycle stage.  
 (planned maintenance type, maintenance type, planned discontinued type, discontinued type)

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